



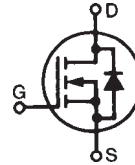
**THE DATASHEET OF
IXFN44N50Q**



HiPerFET™ Power MOSFETs Q-Class

IXFN 44N50Q
IXFN 48N50Q

N-Channel Enhancement Mode
Avalanche Rated, Low Q_g , High dv/dt

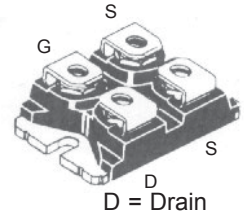


| V_{DSS} | I_{D25} | $R_{DS(on)}$ |
|-----------|-----------|--------------|
| 500 V | 44 A | 120 mΩ |
| 500 V | 48 A | 100 mΩ |

$t_{rr} \leq 250$ ns

| Symbol | Test Conditions | Maximum Ratings | |
|---------------|--|-----------------|-----------|
| V_{DSS} | $T_J = 25^\circ\text{C}$ to 150°C | 500 | V |
| V_{DGR} | $T_J = 25^\circ\text{C}$ to 150°C ; $R_{GS} = 1$ MΩ | 500 | V |
| V_{GS} | Continuous | ±20 | V |
| V_{GSM} | Transient | ±30 | V |
| I_{D25} | $T_C = 25^\circ\text{C}$ | 44N50 | 44 A |
| | | 48N50 | 48 A |
| I_{DM} | $T_C = 25^\circ\text{C}$, pulse width limited by T_{JM} | 44N50 | 176 A |
| | | 48N50 | 192 A |
| I_{AR} | $T_C = 25^\circ\text{C}$ | 48 | A |
| E_{AR} | $T_C = 25^\circ\text{C}$ | 60 | mJ |
| E_{AS} | | 2.5 | mJ |
| dv/dt | $I_S \leq I_{DM}$, $di/dt \leq 100$ A/μs, $V_{DD} \leq V_{DSS}$, $T_J \leq 150^\circ\text{C}$, $R_G = 2$ Ω | 15 | V/ns |
| P_D | $T_C = 25^\circ\text{C}$ | 500 | W |
| T_J | | -55 to +150 | °C |
| T_{JM} | | 150 | °C |
| T_{stg} | | -55 to +150 | °C |
| V_{ISOL} | 50/60 Hz, RMS $t = 1$ min | 2500 | V~ |
| | $I_{ISOL} \leq 1$ mA $t = 1$ s | 3000 | V~ |
| M_d | Mounting torque | 1.5/13 | Nm/lb.in. |
| | Terminal connection torque | 1.5/13 | Nm/lb.in. |
| Weight | | 30 | g |

miniBLOC, SOT-227 B (IXFN)
E153432



G = Gate
S = Source

Either Source terminal at miniBLOC can be used as Main or Kelvin Source

Features

- IXYS advanced low Q_g process
- Low gate charge and capacitances
 - easier to drive
 - faster switching
- Unclamped Inductive Switching (UIS) rated
- Low $R_{DS(on)}$
- Fast intrinsic diode
- International standard package
- miniBLOC with Aluminium nitride isolation for low thermal resistance
- Low terminal inductance (<10 nH) and stray capacitance to heatsink (<35pf)
- Molding epoxies meet UL 94 V-0 flammability classification

Applications

- DC-DC converters
- Battery chargers
- Switched-mode and resonant-mode power supplies
- DC choppers
- Temperature and lighting controls

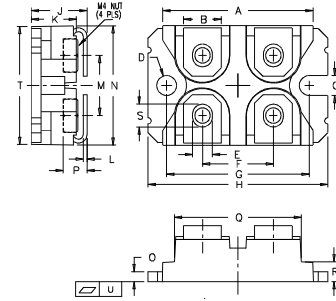
Advantages

- Easy to mount
- Space savings
- High power density

| Symbol | Test Conditions | Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified) | | |
|--------------|--|---|------|---------|
| | | min. | typ. | max. |
| V_{DSS} | $V_{GS} = 0$ V, $I_D = 1$ mA | 500 | | V |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = 4$ mA | 2.0 | | V |
| I_{GSS} | $V_{GS} = \pm 20$ V _{DC} , $V_{DS} = 0$ | | | ±100 nA |
| I_{DSS} | $V_{DS} = V_{DSS}$ $V_{GS} = 0$ V | $T_J = 25^\circ\text{C}$ | | 100 μA |
| | | $T_J = 125^\circ\text{C}$ | | 2 mA |
| $R_{DS(on)}$ | $V_{GS} = 10$ V, $I_D = 0.5$ I_{D25} Pulse test, $t \leq 300$ μs, duty cycle $d \leq 2$ % | 44N50 | | 120 Ω |
| | | 48N50 | | 100 Ω |

| Symbol | Test Conditions | Characteristic Values | | |
|---------------------------|--|---|------|------|
| | | (T _J = 25°C, unless otherwise specified) | | |
| | | min. | typ. | max. |
| g_{fs} | V _{DS} = 20 V; I _D = 0.5 • I _{D25} , pulse test | 30 | 42 | S |
| C_{iss} | V _{GS} = 0 V, V _{DS} = 25 V, f = 1 MHz | | 7000 | pF |
| C_{oss} | | | 960 | pF |
| C_{rss} | | | 230 | pF |
| t_{d(on)} | V _{GS} = 10 V, V _{DS} = 0.5 • V _{DSS} , I _D = 0.5 • I _{D25} R _G = 4.7 Ω (External), | | 33 | ns |
| t_r | | | 22 | ns |
| t_{d(off)} | | | 75 | ns |
| t_f | | | 10 | ns |
| Q_{g(on)} | V _{GS} = 10 V, V _{DS} = 0.5 • V _{DSS} , I _D = 0.5 • I _{D25} | | 190 | nC |
| Q_{gs} | | | 40 | nC |
| Q_{gd} | | | 86 | nC |
| R_{thJC} | | | 0.26 | K/W |
| R_{thCK} | | | 0.05 | K/W |

| Symbol | Test Conditions | Characteristic Values | | |
|-----------------------|--|---|------|--------|
| | | (T _J = 25°C, unless otherwise specified) | | |
| | | min. | typ. | max. |
| I_S | V _{GS} = 0 V | | | 48 A |
| I_{SM} | Repetitive; pulse width limited by T _{JM} | | | 192 A |
| V_{SD} | I _F = I _S , V _{GS} = 0 V, Pulse test, t ≤ 300 μs, duty cycle d ≤ 2 % | | | 1.5 V |
| t_{rr} | I _F = 25A, -di/dt = 100 A/μs, V _R = 100 V | | | 250 ns |
| Q_{RM} | | | 1.0 | μC |
| I_{RM} | | | 10 | A |

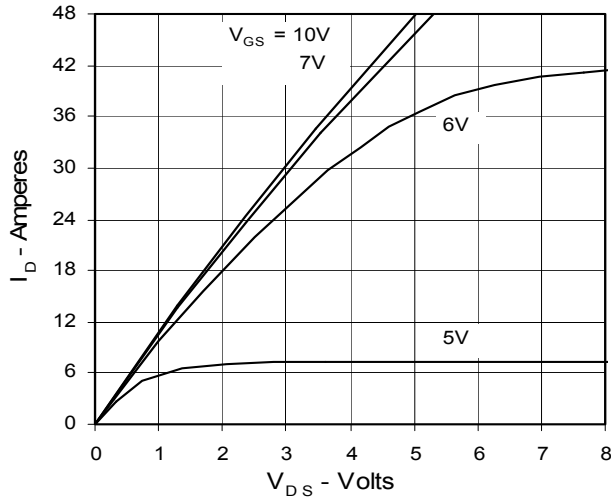
miniBLOC, SOT-227 B


M4 screws (4x) supplied

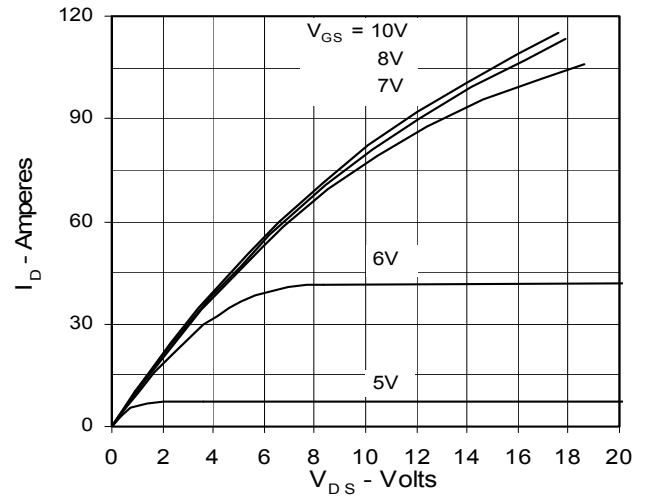
| Dim. | Millimeter | | Inches | |
|------|------------|-------|--------|-------|
| | Min. | Max. | Min. | Max. |
| A | 31.50 | 31.88 | 1.240 | 1.255 |
| B | 7.80 | 8.20 | 0.307 | 0.323 |
| C | 4.09 | 4.29 | 0.161 | 0.169 |
| D | 4.09 | 4.29 | 0.161 | 0.169 |
| E | 4.09 | 4.29 | 0.161 | 0.169 |
| F | 14.91 | 15.11 | 0.587 | 0.595 |
| G | 30.12 | 30.30 | 1.186 | 1.193 |
| H | 38.00 | 38.23 | 1.496 | 1.505 |
| J | 11.68 | 12.22 | 0.460 | 0.481 |
| K | 8.92 | 9.60 | 0.351 | 0.378 |
| L | 0.76 | 0.84 | 0.030 | 0.033 |
| M | 12.60 | 12.85 | 0.496 | 0.506 |
| N | 25.15 | 25.42 | 0.990 | 1.001 |
| O | 1.98 | 2.13 | 0.078 | 0.084 |
| P | 4.95 | 5.97 | 0.195 | 0.235 |
| Q | 26.54 | 26.90 | 1.045 | 1.059 |
| R | 3.94 | 4.42 | 0.155 | 0.174 |
| S | 4.72 | 4.85 | 0.186 | 0.191 |
| T | 24.59 | 25.07 | 0.968 | 0.987 |
| U | -0.05 | 0.1 | -0.002 | 0.004 |

IXYS reserves the right to change limits, test conditions, and dimensions.

**Fig. 1. Output Characteristics
@ 25 Deg. C**



**Fig. 2. Extended Output Characteristics
@ 25 deg. C**



**Fig. 3. Output Characteristics
@ 125 Deg. C**

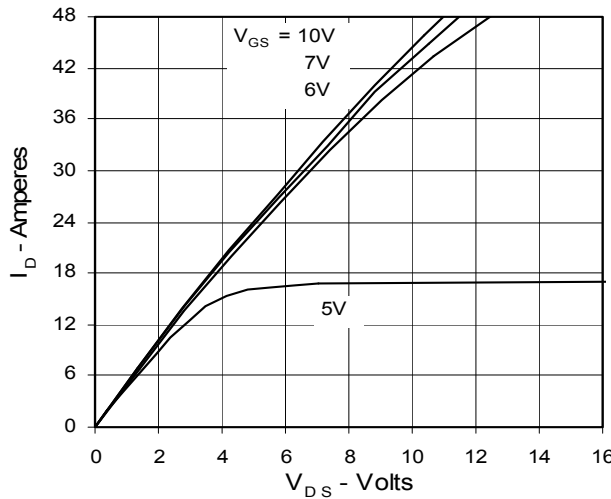


Fig. 4. $R_{DS(on)}$ Normalized to I_{D25} Value vs. Junction Temperature

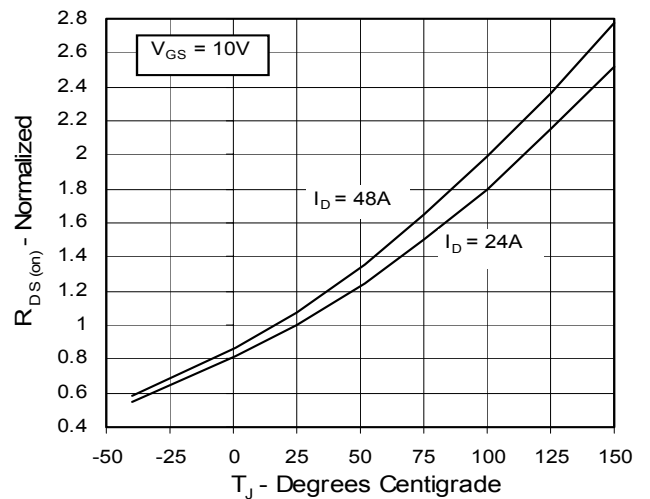


Fig. 5. $R_{DS(on)}$ Normalized to I_{D25} Value vs. I_D

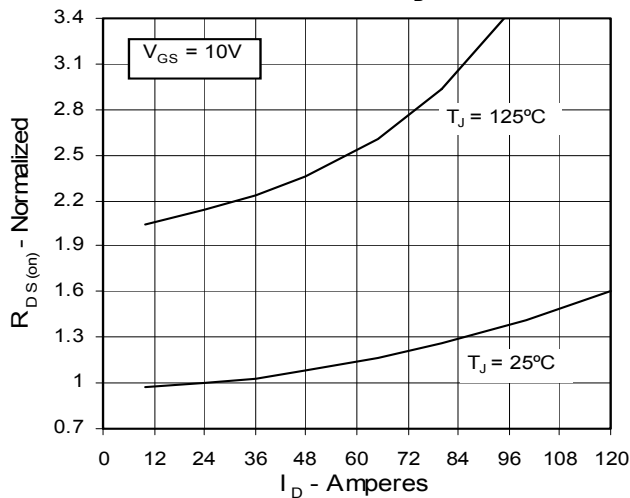


Fig. 6. Drain Current vs. Case Temperature

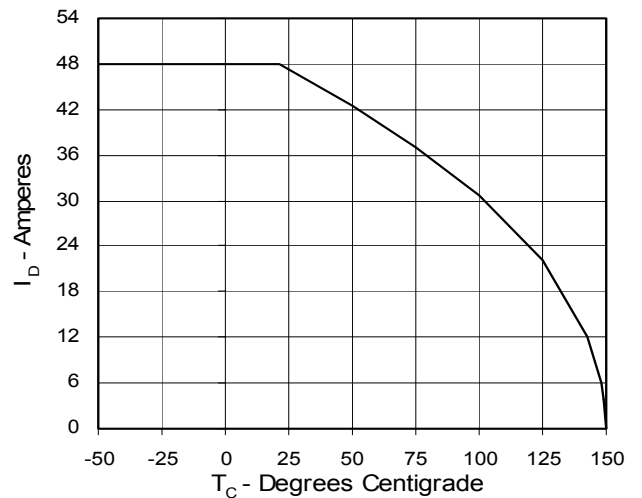


Fig. 7. Input Admittance

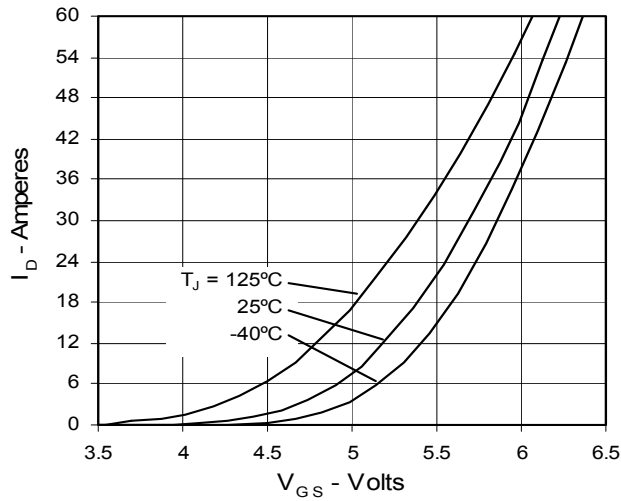


Fig. 8. Transconductance

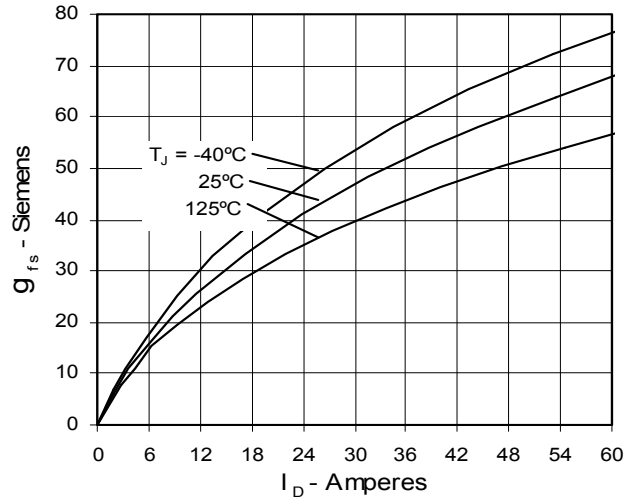


Fig. 9. Source Current vs. Source-To-Drain Voltage

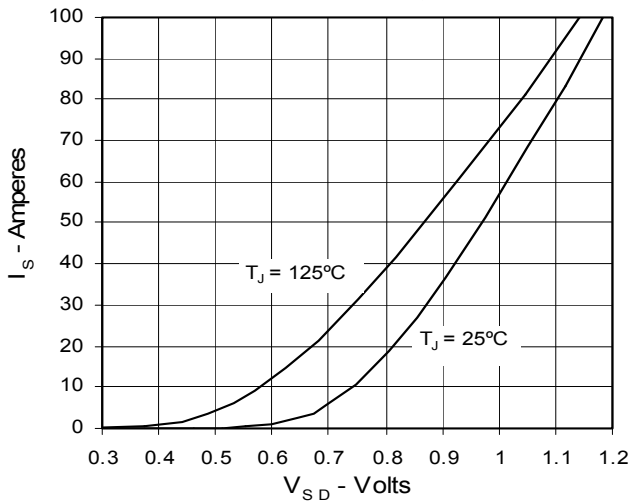


Fig. 10. Gate Charge

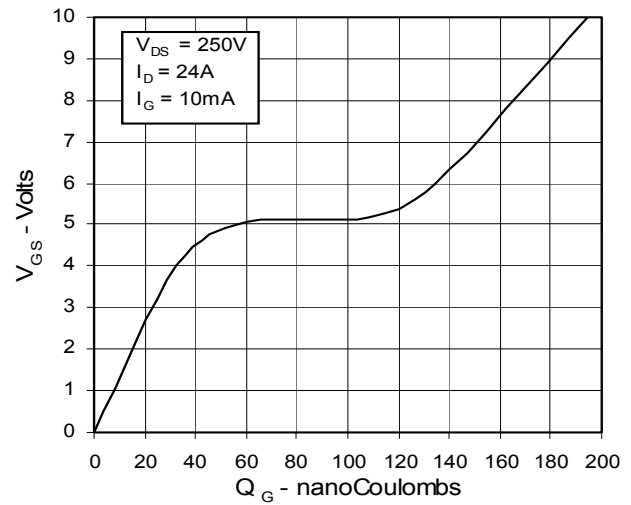


Fig. 11. Capacitance

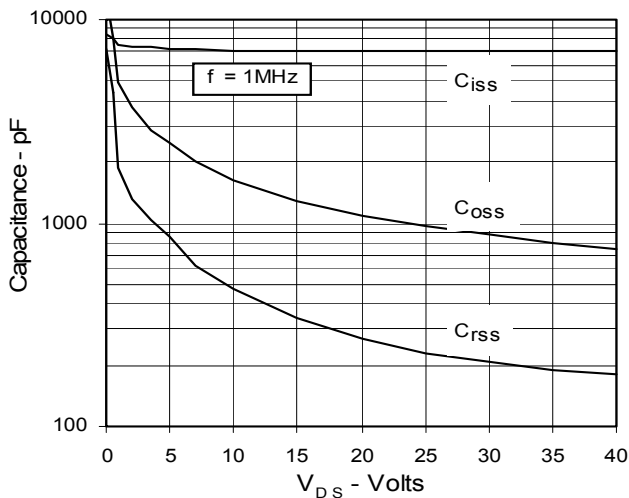
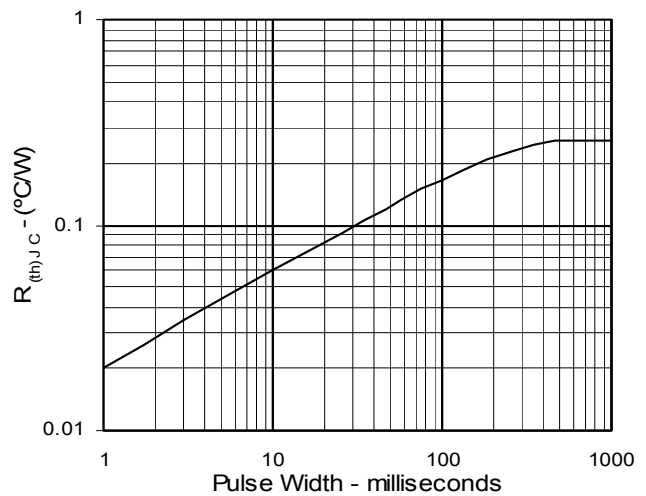


Fig. 12. Maximum Transient Thermal Resistance



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